

N-channel 30 V, 0.70 mOhm, ASFET for hotswap with enhanced SOA in LFPAK56E 10 November 2022 Product d

Product data sheet

1. General description

N-channel enhancement mode ASFET for hotswap with enhanced SOA in LFPAK56E package optimized for low R_{DSon} and strong safe operating area, optimized for hot-swap, inrush and linear-mode applications.

2. Features and benefits

- Fully optimized Safe Operating Area (SOA) for superior linear mode operation
- Optimized for low R_{DSon} / low I²R conduction losses
- LFPAK56E package for applications that demand the highest performance and reliability in a 30 mm² footprint
- Low leakage <1 µA at 25 °C
- Copper-clip for low parasitic inductance and resistance
- High reliability LFPAK package, qualified to 175 °C

3. Applications

- Hot swap in 12 V-20 V applications
- e-Fuse
- DC switch
- Load switch
- Battery protection

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	30	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	365	А
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	333	W
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10		-	0.64	0.7	mΩ
		V _{GS} = 7 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 10</u>		-	0.75	1	mΩ
Dynamic ch	naracteristics						
Q _{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V;		2	13	26	nC
Q _{G(tot)}	total gate charge	T _j = 25 °C; <u>Fig. 12; Fig. 13</u>		23	52	86	nC

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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
Source-drain d	iode					
S		$I_{S} = 25 \text{ A}; \text{ d}I_{S}/\text{d}t = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V}; \\ \text{V}_{DS} = 15 \text{ V}; \text{ T}_{j} = 25 ^{\circ}\text{C}; \text{ Fig. 16}$	-	0.94	-	

[1] 365 A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	rech	
2	S	source		
3	S	source		D
4	G	gate		
mb	D	mounting base; connected to drain		G HEAD MEDDOTE S
			LFPAK56E; Power- SO8 (SOT1023)	

6. Ordering information

Table 3. Ordering information

Type number	Package	'ackage					
	Name	Description	Version				
PSMNR67-30YLE	LFPAK56E; Power-SO8	plastic, single-ended surface-mounted package (LFPAK56); 4 leads; 1.27 mm pitch	SOT1023				

7. Marking

Table 4. Marking codes	
Type number	Marking code
PSMNR67-30YLE	E67L30J

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Tj = 25 °C unless otherwise stated.

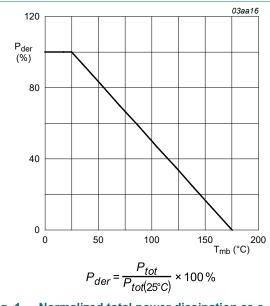
Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	30	V
V _{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	30	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	333	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	365	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	361	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	2070	А

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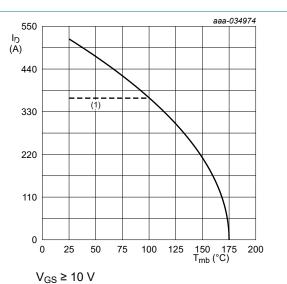
Symbol	Parameter	Conditions		Min	Мах	Unit
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain	n diode					
I _S	source current	T _{mb} = 25 °C		-	333	А
I _{SM}	peak source current	pulsed; t _p ≤ 10 µs; T _{mb} = 25 °C		-	2070	А
Avalanche r	uggedness					
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$ \begin{array}{l} {\sf I}_{\sf D} = 25 \; {\sf A}; \; {\sf V}_{sup} \leq \; 30 \; {\sf V}; \; {\sf R}_{\sf GS} = 50 \; \Omega; \\ {\sf V}_{\sf GS} = 10 \; {\sf V}; \; {\sf T}_{j(init)} = 25 \; {}^\circ{\sf C}; \; unclamped; \\ {\sf t}_p = 10 \; ms \end{array} $	[2]	-	4.9	J
I _{AS}	non-repetitive avalanche current		[2]	-	190	A

[1] 365 A Continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test.



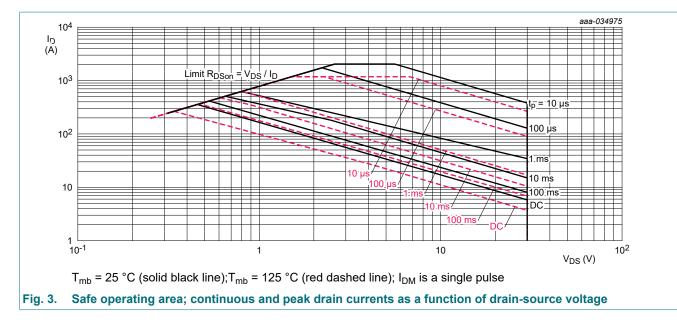




(1) 365 A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

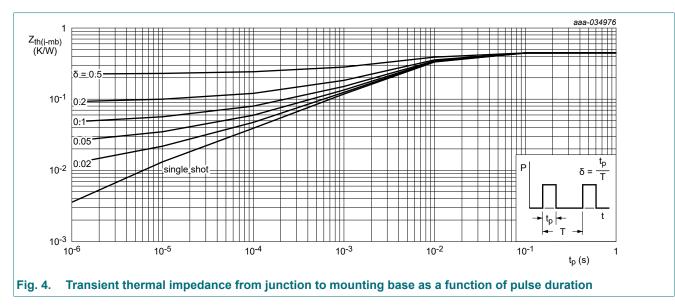
Fig. 2. Continuous drain current as a function of mounting base temperature

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9. Thermal characteristics

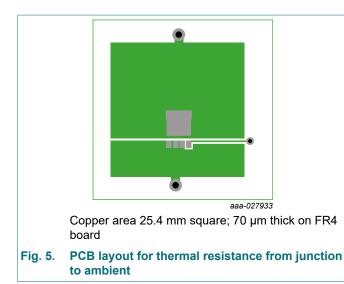
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 4</u>	-	0.34	0.45	K/W
R _{th(j-a)}	thermal resistance from	<u>Fig. 5</u>	-	42	-	K/W
junction to ambient	Fig. 6	-	85	-	K/W	



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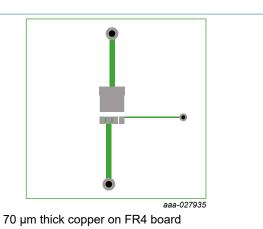


Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

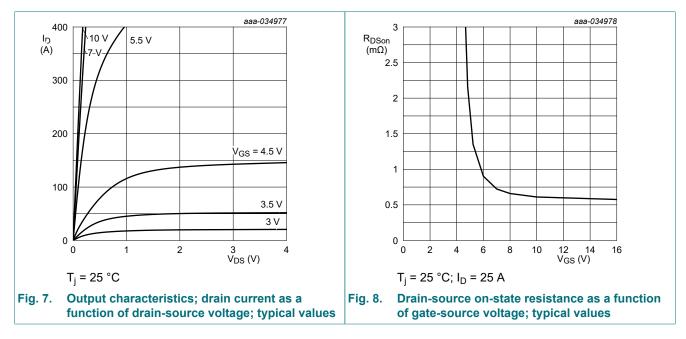
10. Characteristics

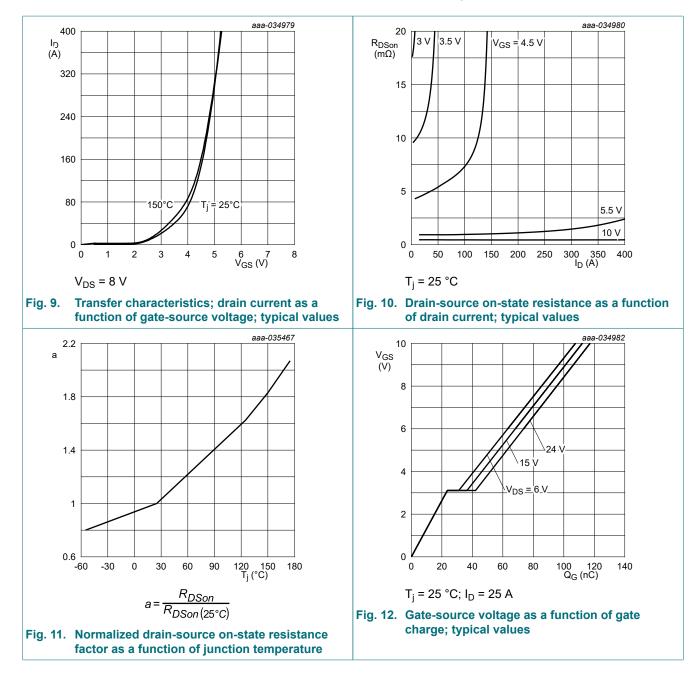
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
Static charac	teristics	· · ·	I				
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V	
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	27	-	-	V	
V _{GS(th)}	gate-source threshold voltage	$I_D = 2 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.79	2.2	V	
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-3.9	-	mV/K	
I _{DSS}	drain leakage current	V _{DS} = 24 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA	
		V _{DS} = 24 V; V _{GS} = 0 V; T _j = 125 °C	-	10	-	μA	
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA	
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA	
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 25 A; T _j = 25 °C; Fig. 10	-	0.64	0.7	mΩ	
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; <u>Fig. 11</u>	-	-	1.3	mΩ	
		V _{GS} = 7 V; I _D = 25 A; T _j = 25 °C; <u>Fig. 10</u>	-	0.75	1	mΩ	
		V _{GS} = 7 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	1.9	mΩ	
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	1.4	3.6	9	Ω	
Dynamic cha	racteristics	·					
Q _{G(tot)}	total gate charge	I_D = 25 A; V_{DS} = 15 V; V_{GS} = 4.5 V; T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>	23	52	86	nC	
			I_D = 25 A; V_{DS} = 15 V; V_{GS} = 10 V; T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>	50	112	185	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V; T _i = 25 °C	-	60	-	nC	

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V;		6.5	24	46	nC
Q _{GS(th)}	pre-threshold gate- source charge	[–] T _j = 25 °C; <u>Fig. 12</u> ; <u>Fig. 13</u>		3.5	13	25	nC
Q _{GS(th-pl)}	post-threshold gate- source charge	-		3	11	21	nC
Q _{GD}	gate-drain charge			2	13	26	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 25 A; V _{DS} = 15 V; T _j = 25 °C; Fig. 12; Fig. 13		-	3.1	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;		4967	8278	12417	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u> 		1542	2570	3855	pF
C _{rss}	reverse transfer capacitance			117	435	1044	pF
t _{d(on)}	turn-on delay time			-	64	-	ns
t _r	rise time			-	124	-	ns
t _{d(off)}	turn-off delay time			-	52	-	ns
t _f	fall time			-	59	-	ns
Q _{oss}	output charge	V _{GS} = 0 V; V _{DS} = 15 V; f = 1 MHz; T _j = 25 °C		-	62	-	nC
Source-drai	in diode	1		-	-		
V _{SD}	source-drain voltage	I_{S} = 25 A; V_{GS} = 0 V; T_{j} = 25 °C; <u>Fig. 15</u>		-	0.77	1	V
t _{rr}	reverse recovery time	$I_{S} = 25 \text{ A}; \text{ dI}_{S}/\text{dt} = -100 \text{ A}/\mu\text{s}; \text{ V}_{GS} = 0 \text{ V};$		-	42	-	ns
Q _r	recovered charge	V _{DS} = 15 V; T _j = 25 °C; <u>Fig. 16</u>	[1]	-	42	-	nC
t _a	reverse recovery rise time			-	21.5	-	ns
t _b	reverse recovery fall time			-	20.3	-	ns
S	softness factor	1		-	0.94	-	

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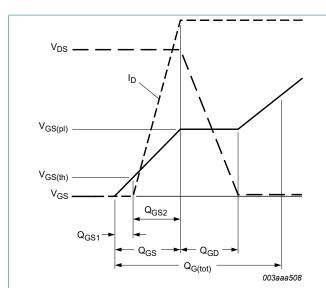
[1] includes capacitive recovery



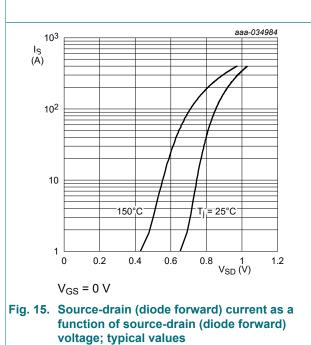


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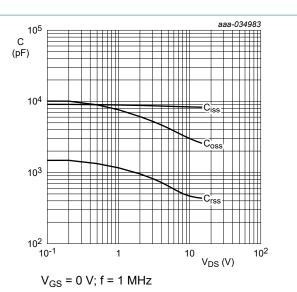
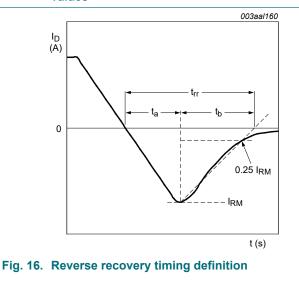
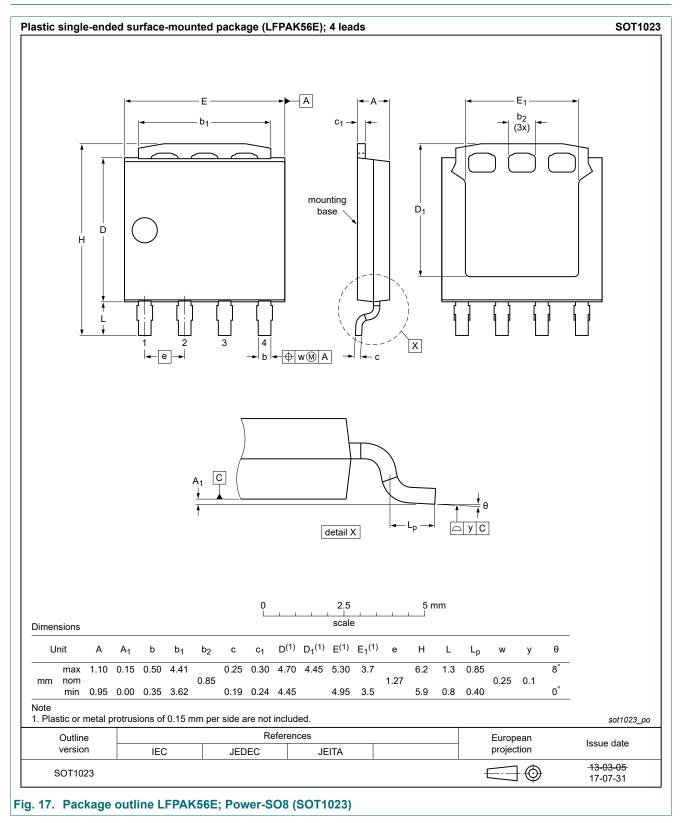


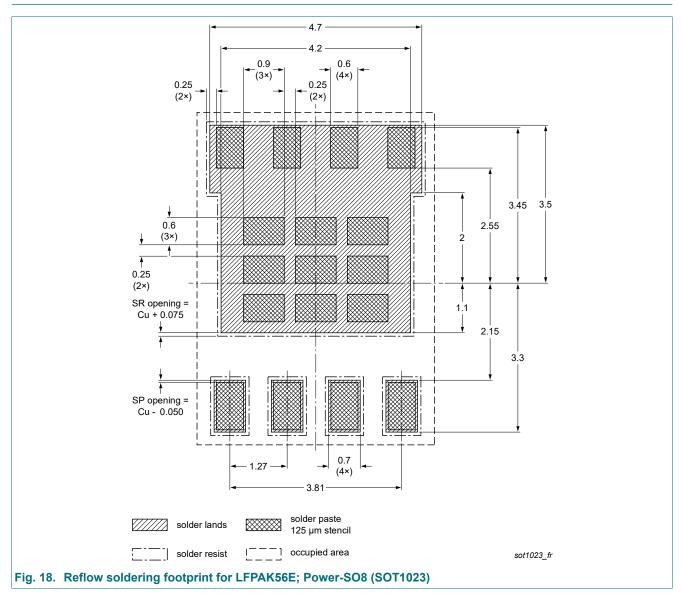
Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



11. Package outline



12. Soldering



13. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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 Please consult the most recently issued document before initiating or completing a design.

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